NSN 5961-01-049-8100

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-049-8100 **Inclosure Material:** Metal **Overall Length:** 0.065 inches **Overall Diameter:** 0.122 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 70.0 reverse breakdown voltage, dc **Current Rating Per Characteristic:** 10.00 microamperes forward current, average horsepower metric **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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